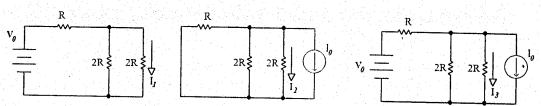
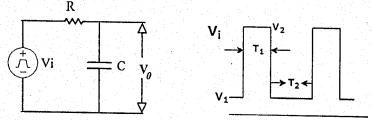
國立中央大學96學年度碩士班考試入學試題卷 #_2_頁 第_/ 頁

所別:<u>光電科學研究所碩士班一般生</u>科目:<u>電子學</u>學位在職生

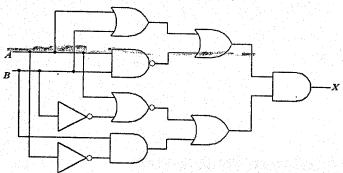
15% 1. Find the currents, I_1 , I_2 , and I_3 in terms of V_0 , I_0 , and R. Then, express the relation among I_1 , I_2 , and I_3 .



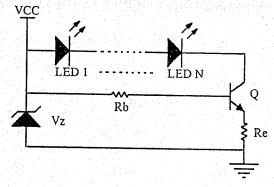
15% 2. Refer to the circuit below. Please discuss the characteristics of the output V_o in terms of the parameters of V_1 , V_2 , T_1 , and T_2 for V_i .



15% 3. Simplify the logic circuit with as few logic gates as possible (AND, OR, and NOT gates only). A and B are two input ports, and X is the output port.



20% 4. Derive the electric current, I_{f} through LEDs. If each LED has a voltage drop V_{f} evaluate the maximum possible number of LEDs.

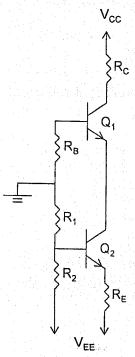


注:背面有試題

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所別:<u>光電科學研究所碩士班一般生</u>科目:<u>電子學</u>學位在職生

- 20% 5.Please design the BJT circuit, and find out R1, R2, RB, RC, RE :
 - (1)When current gain $\, \beta \,$ is infinity, $\, I_{\rm C1} = 0.1 \, {\rm mA} \, \cdot \, V_{\rm RE} = 2 \, {\rm V} \,$ and $\, V_{\rm CE1} = 1.5 \, {\rm V} \,$;
 - (2)When current gain β is 50, V_{CE1} =2.5V and V_{R_E} reduced 5%



15% 6.Please find out these circuit symbols :

- (1)Zerner Diode (2)npn BJT (3)p-channel MOSFET
- (4)n-channel depletion-type MOSFET(5)n-channel JFET

